

GaAs SP4T Switch, Absorptive DC - 3.0 GHz

Rev. V7

Features

- Typical Isolation: 35 dB (2.0 GHz)
 Typical Insertion Loss: 1.2 dB (2.0 GHz)
- Integral ASIC/CMOS Driver
- 50 Ohm Nominal Impedance
- · Low DC Power Consumption
- Test Boards Available
- Lead-Free QSOP-24 Package
- 100% Matte Tin Plating over Copper
- · Halogen-Free "Green" Mold Compound
- 260°C Reflow Compatible
- RoHS* Compliant Version of SW65-0440

Description

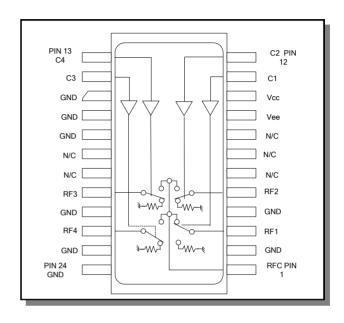
M/A-COM's MASWCC0009 is a GaAs MMIC absorptive SP4T switch with an integral silicon ASIC driver. This device is in a 24-lead plastic package. This switch offers excellent broadband performance and repeatability from DC to 3 GHz, while maintaining low DC power dissipation. The MASWCC0009 is ideally suited for wireless infrastructure applications.

Ordering Information

Part Number	Package
MASWCC0009	Bulk Packaging
MASWCC0009TR	1000 piece reel
MASWCC0009-TB	Sample Test Board

Note: Reference Application Note M513 for reel size information.

Functional Schematic



Pin Configuration

Pin No.	No. Function Pin No.		Function	
1	RFC	13	C4	
2	GND	14	C3	
3	RF1 15		GND	
4	GND	16	GND	
5	RF2	17	GND	
6	NC	18	NC	
7	NC	19	NC	
8	NC	20	RF3	
9	9 V _{EE} 21		GND	
10	V _{CC}	22	RF4	
11	1 C1 23		GND	
12	C2	24	GND	

NC = No Connection

^{*} Restrictions on Hazardous Substances, European Union Directive 2002/95/EC.



GaAs SP4T Switch, Absorptive DC - 3.0 GHz

Rev. V7

Electrical Specifications: $T_A = 25^{\circ}C$

Parameter	Test Conditions	Units	Min	Тур	Max
Insertion Loss	DC - 2.0 GHz DC - 3.0 GHz	dB dB	_	1.2 1.3	1.8 2.5
Isolation	DC - 2.0 GHz DC - 3.0 GHz	dB dB	32 25	35 29	_
VSWR RF1-RF4 On RF1- RF4 Off RFC RFC	DC - 3.0 GHz DC - 3.0 GHz DC - 2.0 GHz DC - 3.0 GHz	Ratio Ratio Ratio Ratio	_ _ _	1.2:1 1.4:1 1.2:1 1.6:1	1.6:1 1.8:1 1.5:1 2.2:1
Switching Speed ¹ $T_{rise} T_{fall}$ $T_{on} T_{off}$ Transients	10%/90%, 90%/10% 50% TTL to 90%/10% RF In-band (peak to peak)	ns ns mV	_ _ _	15 50 50	50 150 150
1 dB Compression	.05 GHz .5 - 3.0 GHz	dBm dBm	_	+20 +27	_
Input IP ₃	Two tone inputs 0.05 GHz up to +5 dBm 0.5 - 3.0 GHz	dBm dBm	_	+35 +46	_
V _{CC}	_	V	+4.5	+5.0	+5.5
V _{EE}	_	V	-8.0	-5.0	-4.75
V _{IL} V _{IH}	LOW-level input voltage HIGH-level input voltage	V V	0.0 2.0	_	0.8 5.0
lin (Input Leakage Current)	Vin = V _{CC} or GND	uA	-1.0	_	1.0
Icc (Quiescent Supply Current)	Vcntrl = V _{CC} or GND	uA	_	250	400
Δlcc (Additional Supply Current Per TTL Input Pin)	V _{CC} = Max, Vcntrl = V _{CC} - 2.1 V	mA	_	_	1.0
lee	VEE min to max, Vin = V_{IL} or V_{IH}	mA	-1.0	-0.2	

Absolute Maximum Ratings ^{2,3,4}

1. Decoupling capacitors (0.1 $\mu\text{F})$ are required on the power supply lines.

Parameter	Absolute Maximum		
Max. Input Power 0.05 GHz 0.5 - 3.0 GHz	+27 dBm +34 dBm		
V _{CC}	-0.5V ≤ V _{CC} ≤ +7.0V		
V _{EE}	-8.5V ≤ V _{EE} ≤ +0.5V		
V _{CC} - V _{EE}	$-0.5V \le V_{CC} - V_{EE} \le 14.5V$		
Vin ⁵	-0.5V ≤ Vin ≤ V _{CC} + 0.5V		
Operating Temperature	-40°C to +85°C		
Storage Temperature	-65°C to +125°C		

Truth Table (Switch)

TTL			RF Common To:				
C1	C2	C3	C4	RF1	RF2	RF3	RF4
1	0	0	0	On	Off	Off	Off
0	1	0	0	Off	On	Off	Off
0	0	1	0	Off	Off	On	Off
0	0	0	1	Off	Off	Off	On

0 = TTL Low; 1 = TTL High

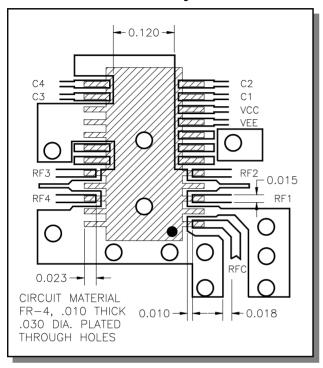
- Exceeding any one or combination of these limits may cause permanent damage to this device.
- M/A-COM does not recommend sustained operation near these survivability limits.
- 4. When the RF input is applied to the terminated port, the absolute maximum power is +30 dBm.
- 5. Standard CMOS TTL interface, latch-up will occur if logic



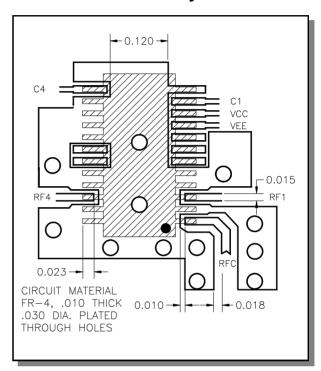
GaAs SP4T Switch, Absorptive DC - 3.0 GHz

Rev. V7

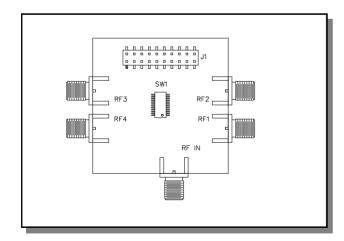
Recommended PCB Layout—SP4T



Recommended PCB Layout—SP2T



Evaluation Board - SW65-0440-TB



Handling Procedures

Please observe the following precautions to avoid damage:

Static Sensitivity

Gallium Arsenide Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.

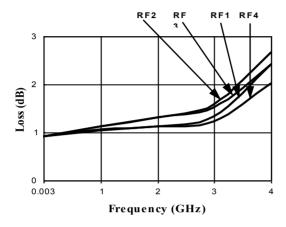


GaAs SP4T Switch, Absorptive DC - 3.0 GHz

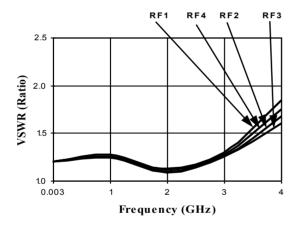
Rev. V7

Typical Performance Curves

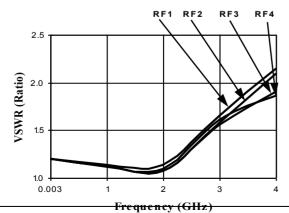
Insertion Loss (dB) @ +25°C



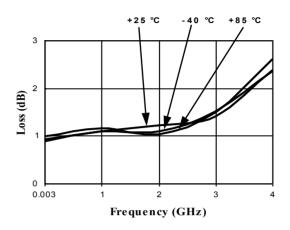
RF1 - RF4 On VSWR @ +25°C



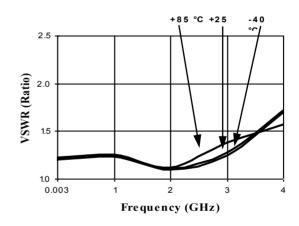
RFC On VSWR @ +25°C



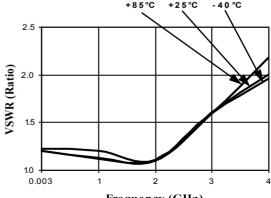
Loss Variation Over Temp. (dB)



RF1 - RF4 On VSWR Temp. Variation



RFC On VSWR Temp. Variation



Frequency (GHz)

M/A-COM Technology Solutions Inc. (MACOM) and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice.

Visit www.macom.com for additional data sheets and product information.

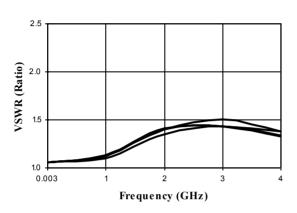


GaAs SP4T Switch, Absorptive DC - 3.0 GHz

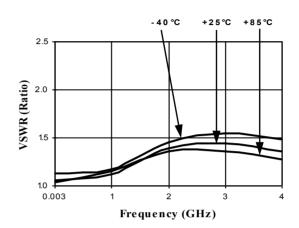
Rev. V7

Typical Performance Curves

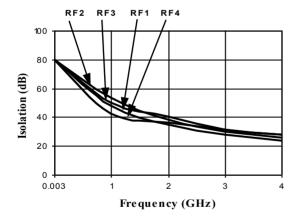
RF1 - RF4 Off VSWR @ +25°C



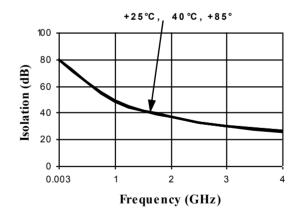
RF1 - RF4 Off VSWR Temp. Variation



Isolation (dB) @ +25°C



Isolation Temp. Variation (dB)

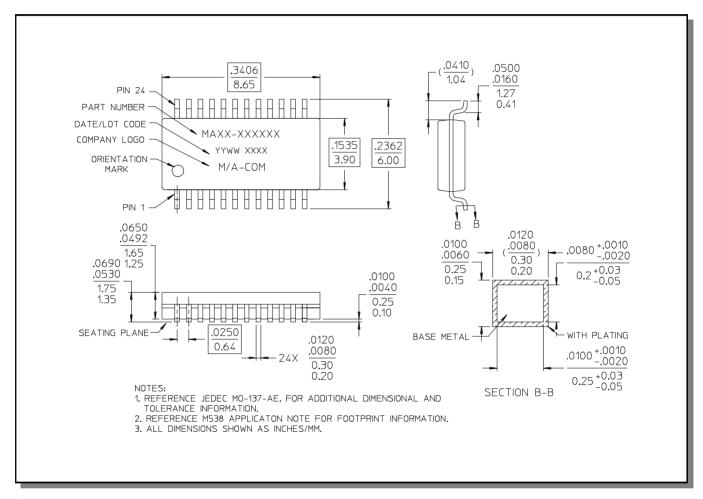




GaAs SP4T Switch, Absorptive DC - 3.0 GHz

Rev. V7

Lead-Free, QSOP-24[†]



[†] Reference Application Note M538 for lead-free solder reflow recommendations.